

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62001P, TD62001AP, TD62001F, TD62001AF, TD62002P, TD62002AP, TD62002F, TD62002AF, TD62003P, TD62003AP, TD62003F, TD62003AF, TD62004P, TD62004AP, TD62004F, TD62004AF

7CH DARLINGTON SINK DRIVER

The TD62001P/AP/F/AF Series are high-voltage, high-current darlington drivers comprised of seven NPN darlington pairs.

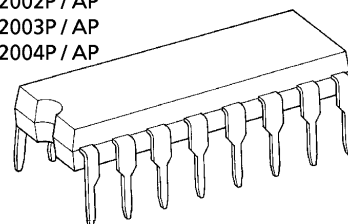
All units feature integral clamp diodes for switching inductive loads.

Applications include relay, hammer, lamp and display (LED) drivers.

FEATURES

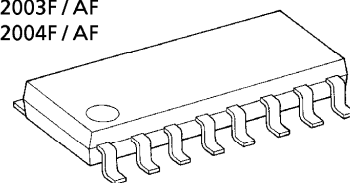
- Output current (single output) 500mA MAX.
- High sustaining voltage output
35V MIN. (TD62001P/F Series)
50V MIN. (TD62001AP/AF Series)
- Output clamp diodes
- Inputs compatible with various types of logic
- Package Type-P, AP : DIP-16pin
- Package Type-F, AF : SOP-16pin

TD62001P/AP
TD62002P/AP
TD62003P/AP
TD62004P/AP



DIP16-P-300-2.54A

TD62001F/AF
TD62002F/AF
TD62003F/AF
TD62004F/AF



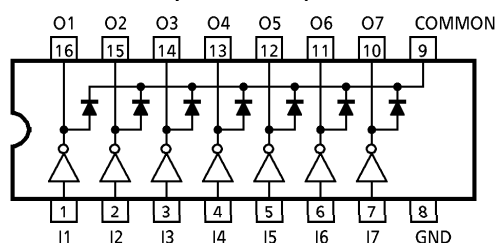
SOP16-P-225-1.27

Weight

DIP16-P-300-2.54A : 1.11g (Typ.)
SOP16-P-225-1.27 : 0.16g (Typ.)

TYPE	INPUT BASE RESISTOR	DESIGNATION
TD62001P/AP/F/AF	External	General Purpose
TD62002P/AP/F/AF	10.5-k Ω + 7V Zenner diode	14~25V PMOS
TD62003P/AP/F/AF	2.7k Ω	TTL, 5V CMOS
TD62004P/AP/F/AF	10.5k Ω	6~15V PMOS, CMOS

PIN CONNECTION (TOP VIEW)

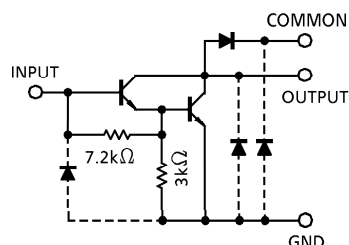


961001EBA2

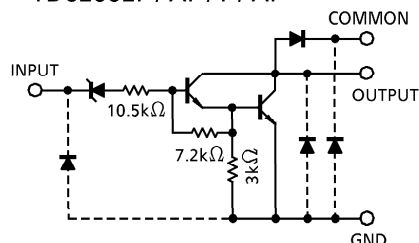
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SCHEMATICS (EACH DRIVER)

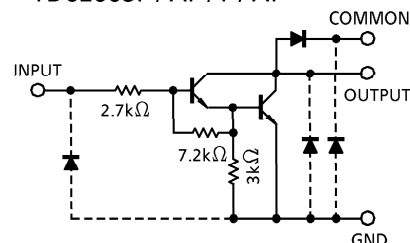
TD62001P / AP / F / AF



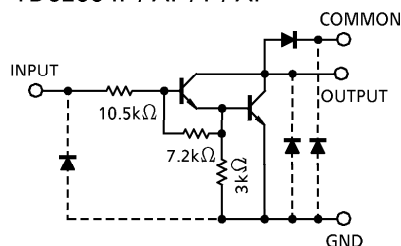
TD62002P / AP / F / AF



TD62003P / AP / F / AF



TD62004P / AP / F / AF



(Note) The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Sustaining Voltage	P, F	$V_{CE(SUS)}$	- 0.5~35	V
	AP, AF		- 0.5~50	
Output Current		I_{OUT}	500	mA / ch
Input Voltage		V_{IN} (Note 1)	- 0.5~30	V
Input Current		I_{IN} (Note 2)	25	mA
Clamp Diode Reverse Voltage	P, F	V_R	35	V
	AP, AF		50	
Clamp Diode Forward Current		I_F	500	mA
Power Dissipation	P	P_D	1.0	W
	AP		1.47	
	F, AF		0.54 / 0.625 (Note 3)	
Operating Temperature	P	T_{opr}	- 30~75	°C
	AP, F, AF		- 40~85	
Storage Temperature		T_{stg}	- 55~150	°C

(Note 1) Except TD62001P / AP / F / AF

(Note 2) Only TD62001P / AP / F / AF

(Note 3) On glass epoxy PCB (30 × 30 × 1.6mm Cu 50%)

RECOMMENDED OPERATING CONDITIONS ($T_a = -40\sim 85^\circ\text{C}$ and $T_a = -30\sim 75^\circ\text{C}$ for only Type-P)

CHARACTERISTIC		SYMBOL	CONDITION		MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage	P, F	$V_{CE(SUS)}$			0	—	35	V
	AP, AF				0	—	50	
Output Current	AP	I_{OUT}	$T_{pw} = 25\text{ms}$ 7 Circuits $T_a = 85^\circ\text{C}$ $T_j = 120^\circ\text{C}$	Duty = 10%	0	—	370	mA / ch
				Duty = 50%	0	—	130	
	P			Duty = 10%	0	—	295	
				Duty = 50%	0	—	95	
	F, AF			Duty = 10%	0	—	233	
				Duty = 50%	0	—	70	
Input Voltage	Except TD62001P / AP / F / AF	V_{IN}			0	—	24	V
Input Voltage (Output On)	TD62002	$V_{IN(ON)}$	$I_{OUT} = 400\text{mA}$ $h_{FE} = 800$		14.5	—	24	V
	TD62003				2.8	—	24	
	TD62004				6.2	—	24	
Input Voltage (Output Off)	TD62001	$V_{IN(OFF)}$			0	—	0.6	V
	TD62002				0	—	7.4	
	TD62003				0	—	0.7	
	TD62004				0	—	1.0	
Input Current	Only TD62001	I_{IN}			0	—	10	mA
Clamp Diode Reverse Voltage	P, F	V_R			—	—	35	V
	AP, AF				—	—	50	
Clamp Diode Forward Current		I_F			—	—	350	mA
Power Dissipation	P	P_D	$T_a = 85^\circ\text{C}$		—	—	0.6	W
	AP				—	—	0.76	
	AF, F		(Note) $T_a = 85^\circ\text{C}$		—	—	0.325	

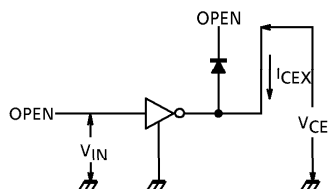
(Note) On glass epoxy PCB (30×30×1.6mm Cu 50%)

ELECTRICAL CHARACTERISTICS (Ta = 25°C unless otherwise noted)

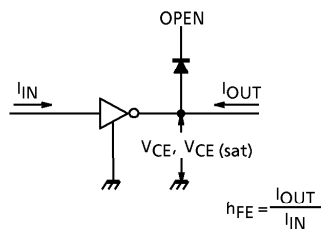
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Output Leakage Current	AP, AF	I _{CEX}	1	V _{CE} = 50V, Ta = 25°C	—	—	50	μA	
				V _{CE} = 50V, Ta = 85°C	—	—	100		
	F			V _{CE} = 35V, Ta = 25°C	—	—	50		
				V _{CE} = 35V, Ta = 85°C	—	—	100		
	P			V _{CE} = 35V, Ta = 25°C	—	—	50		
				V _{CE} = 35V, Ta = 75°C	—	—	100		
Collector-Emitter Saturation Voltage		V _{CE (sat)}	2	I _{OUT} = 350mA, I _{IN} = 500μA	—	1.3	1.6	V	
				I _{OUT} = 200mA, I _{IN} = 350μA	—	1.1	1.3		
				I _{OUT} = 100mA, I _{IN} = 250μA	—	0.9	1.1		
DC Current Transfer Ratio		h _{FE}	2	V _{CE} = 2V, I _{OUT} = 350mA	1000	—	—		
Input Current (Output On)	TD62002	I _{IN (ON)}	3	V _{IN} = 20V, I _{OUT} = 350mA	—	1.1	1.7	mA	
	TD62003			V _{IN} = 2.4V, I _{OUT} = 350mA	—	0.4	0.7		
	TD62004			V _{IN} = 9.5V, I _{OUT} = 350mA	—	0.8	1.2		
Input Current (Output Off)	P	I _{IN (OFF)}	4	I _{OUT} = 500μA, Ta = 75°C	50	65	—	μA	
	AP, F, AF			I _{OUT} = 500μA, Ta = 85°C	50	65	—		
Input Voltage (Output On)	TD62002	V _{IN (ON)}	5	V _{CE} = 2V h _{FE} = 800	I _{OUT} = 350mA	—	—	13.7	V
					I _{OUT} = 200mA	—	—	11.4	
	TD62003				I _{OUT} = 350mA	—	—	2.6	
					I _{OUT} = 200mA	—	—	2.0	
	TD62004				I _{OUT} = 350mA	—	—	4.7	
					I _{OUT} = 200mA	—	—	4.4	
Clamp Diode Reverse Current	AP, AF	I _R	6	V _R = 50V, Ta = 25°C	—	—	50	μA	
				V _R = 50V, Ta = 85°C	—	—	100		
	F			V _R = 35V, Ta = 25°C	—	—	50		
				V _R = 35V, Ta = 85°C	—	—	100		
	P			V _R = 35V, Ta = 25°C	—	—	50		
				V _R = 35V, Ta = 75°C	—	—	100		
Clamp Diode Forward Voltage		V _F	7	I _F = 350mA	—	—	2.0	V	
Input Capacitance		C _{IN}	—		—	15	—	pF	
Turn-On Delay	P, F	t _{ON}	8	V _{OUT} = 35V, R _L = 87.5Ω C _L = 15pF	—	0.1	—	μs	
	AP, AF			V _{OUT} = 50V, R _L = 125Ω C _L = 15pF	—	0.1	—		
Turn-Off Delay	P, F	t _{OFF}	8	V _{OUT} = 35V, R _L = 87.5Ω C _L = 15pF	—	0.2	—		
	AP, AF			V _{OUT} = 50V, R _L = 125Ω C _L = 15pF	—	0.2	—		

TEST CIRCUIT

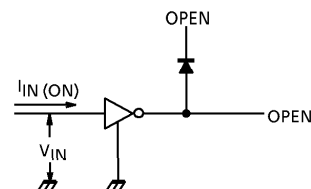
1. I_{CEX}



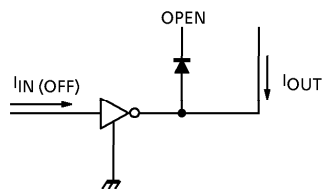
2. $V_{CE(sat)}$, h_{FE}



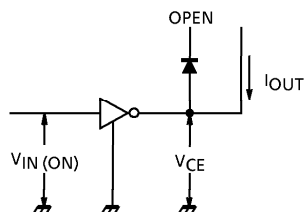
3. $I_{IN(ON)}$



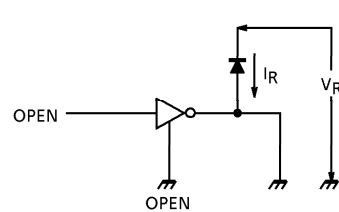
4. $I_{IN(OFF)}$



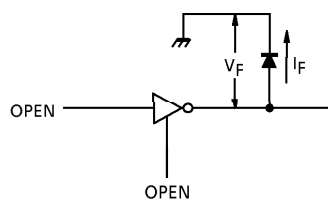
5. $V_{IN(ON)}$

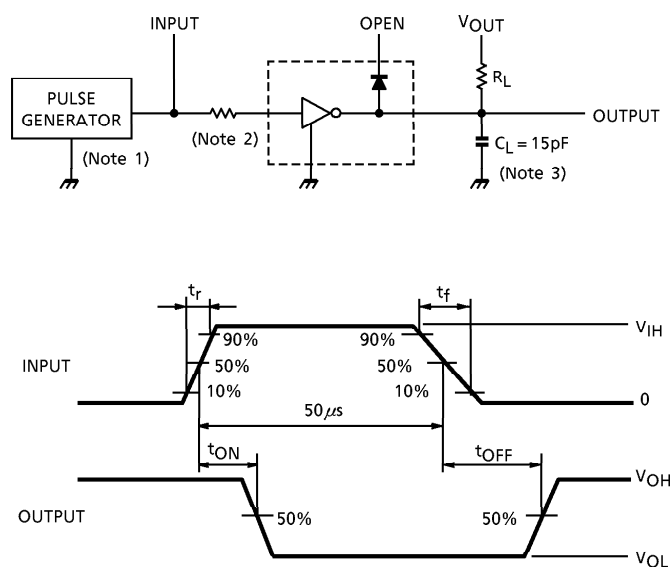


6. I_R



7. V_F



8. t_{ON} , t_{OFF} 

(Note 1) Pulse width $50\mu\text{s}$, duty cycle 10%
Output impedance 50Ω , $t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$

(Note 2) See below

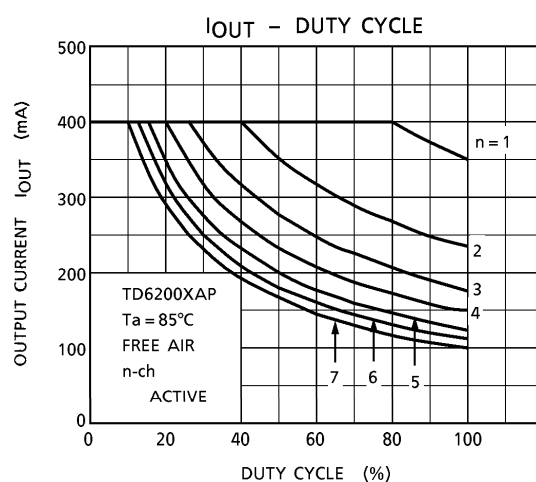
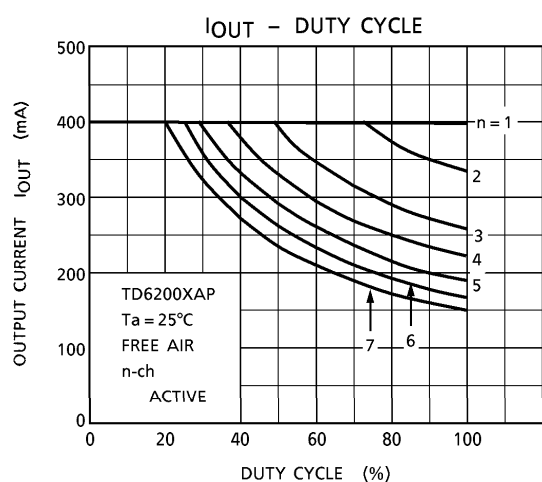
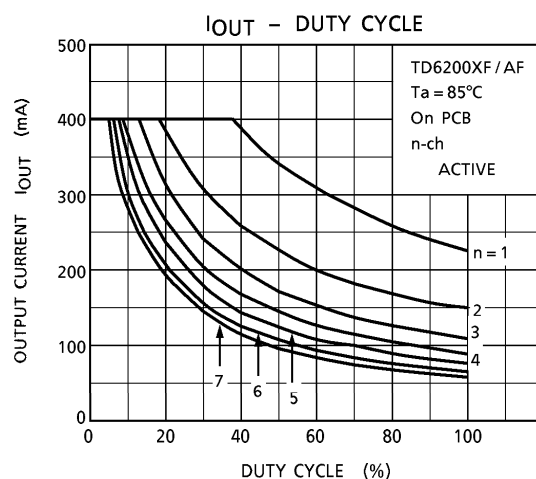
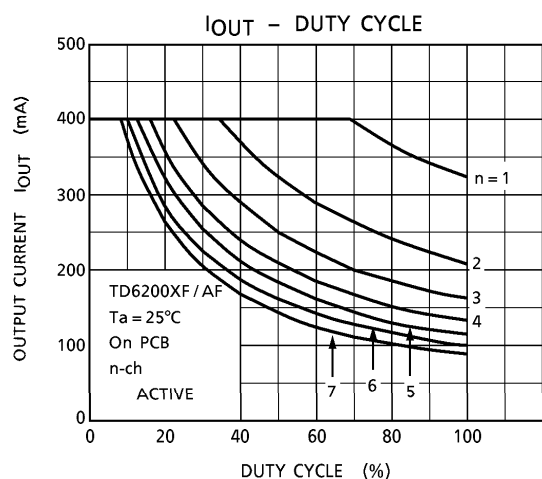
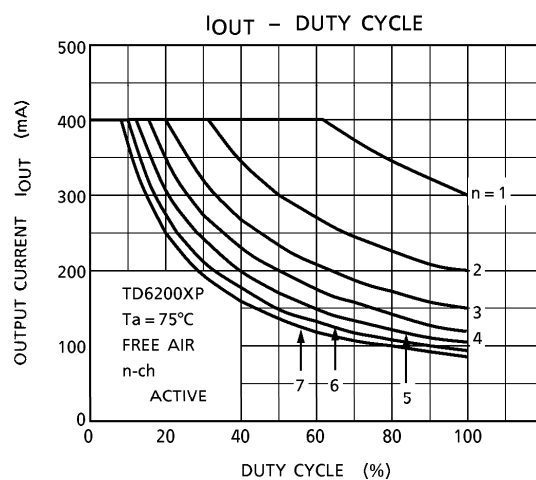
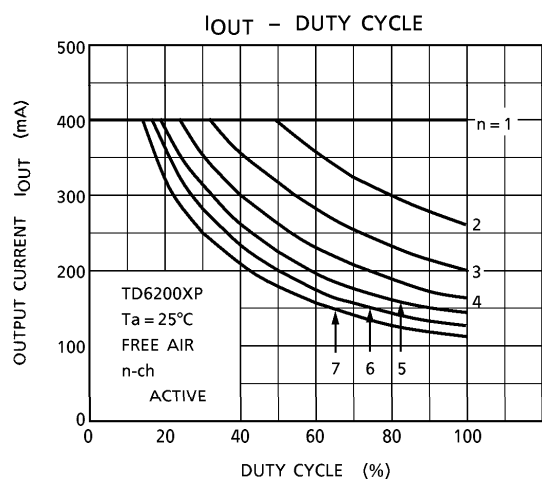
INPUT CONDITION

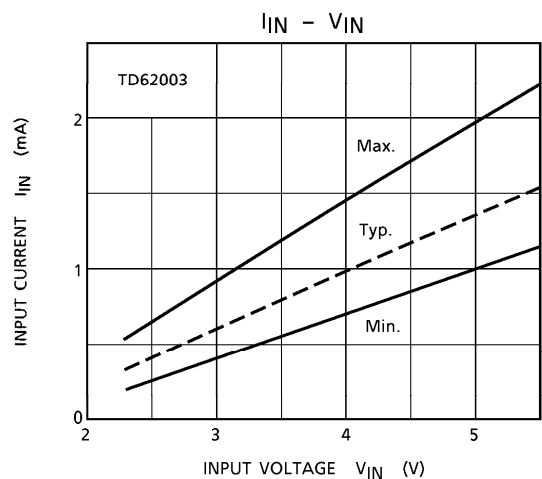
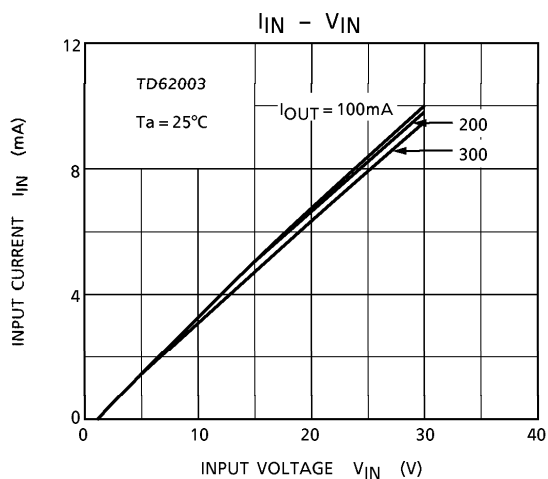
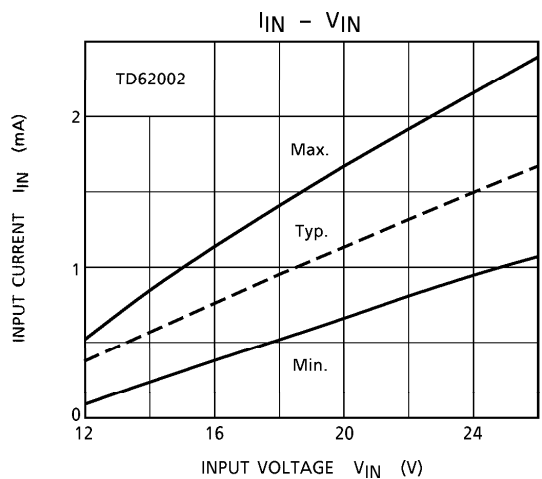
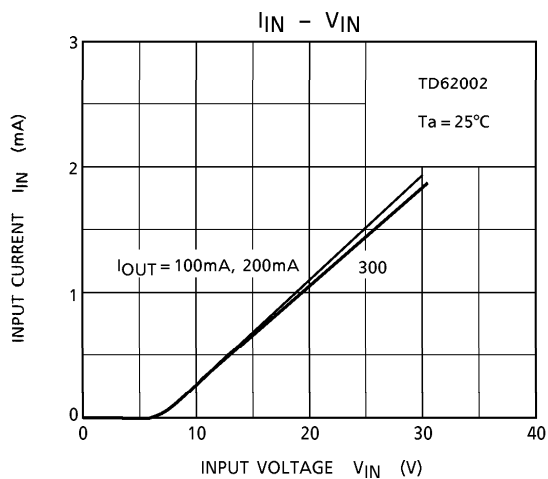
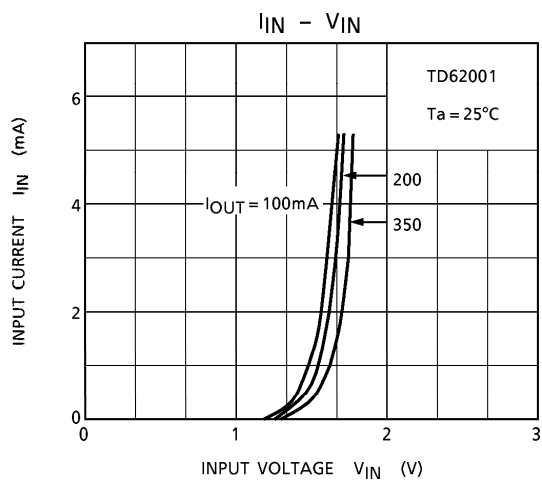
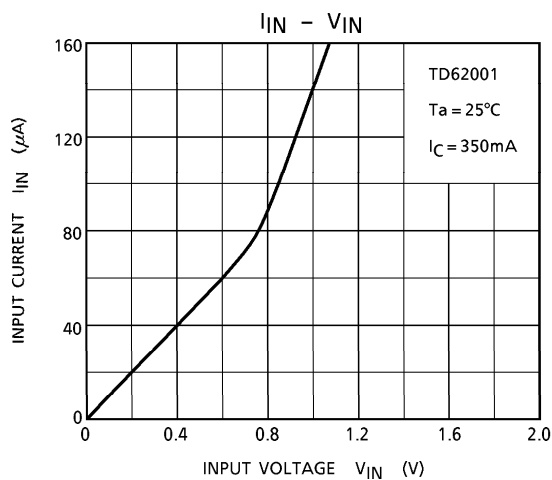
TYPE NUMBER	R1	V_{IH}
TD62001P / AP / F / AF	$2.7\text{k}\Omega$	3V
TD62002P / AP / F / AF	0	13V
TD62003P / AP / F / AF	0	3V
TD62004P / AP / F / AF	0	8V

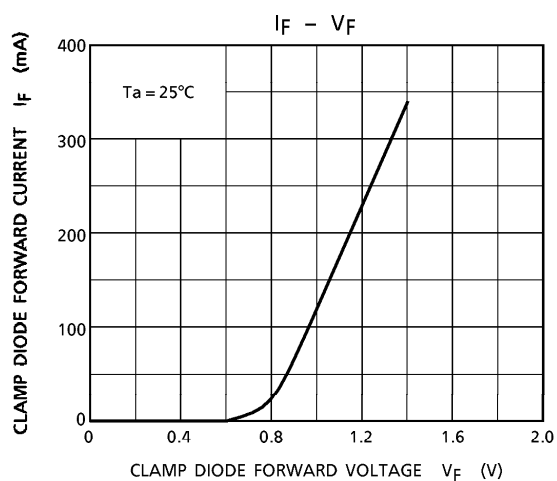
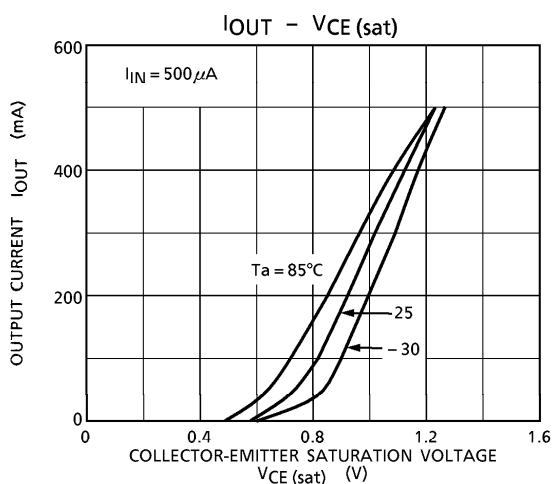
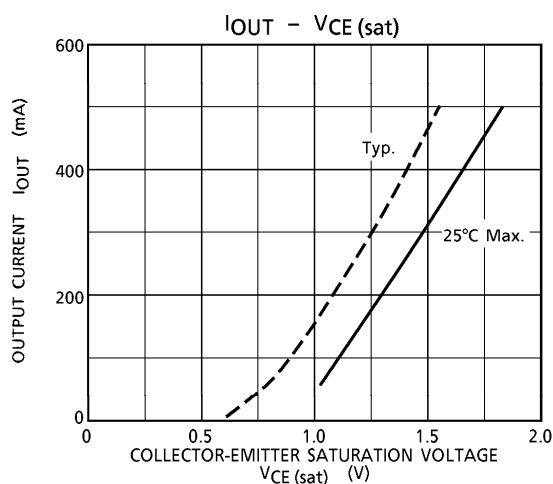
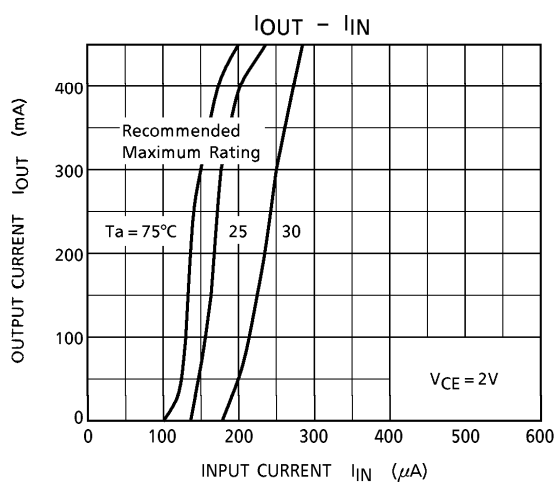
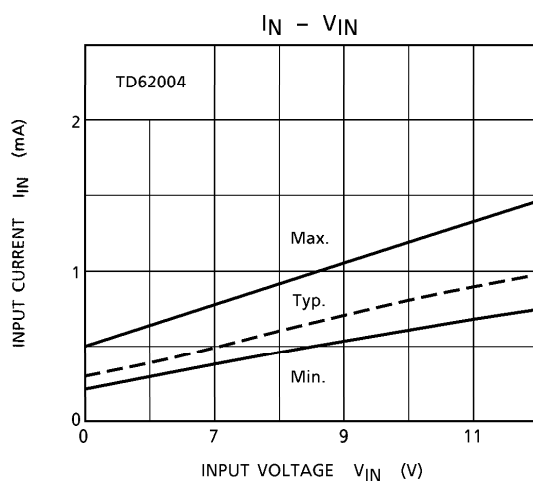
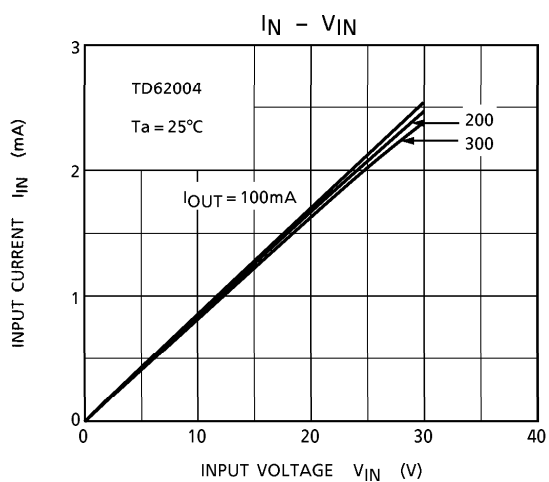
(Note 3) C_L includes probe and jig capacitance.

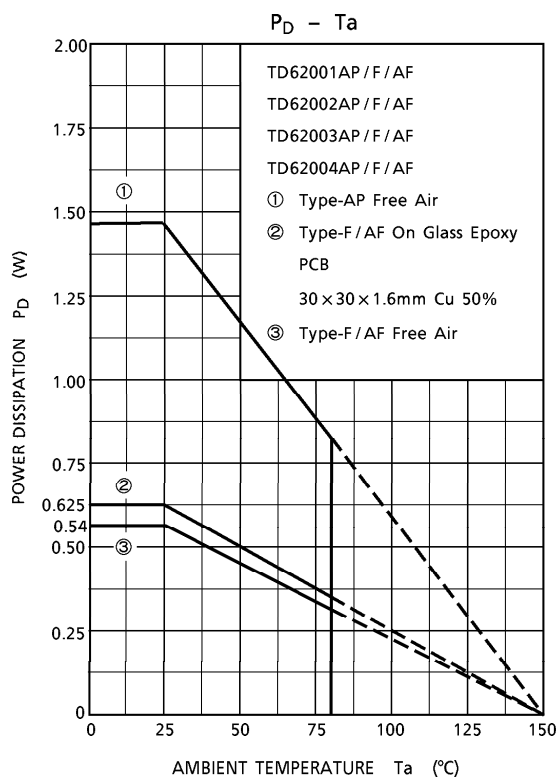
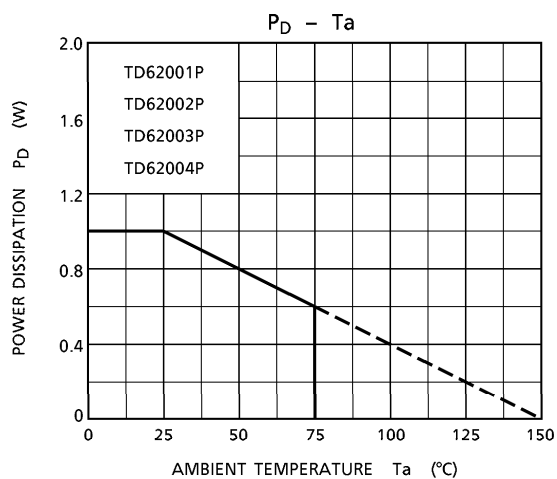
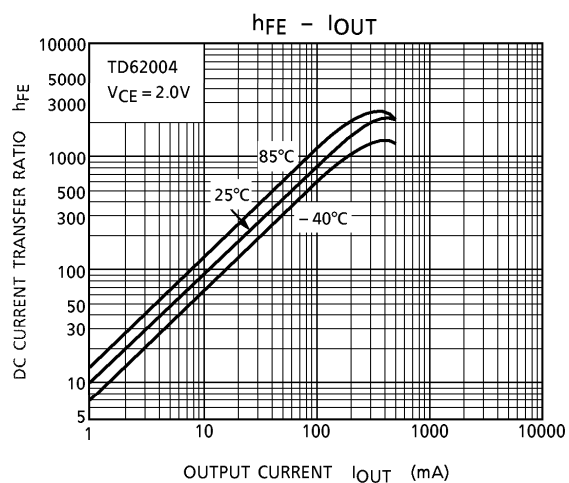
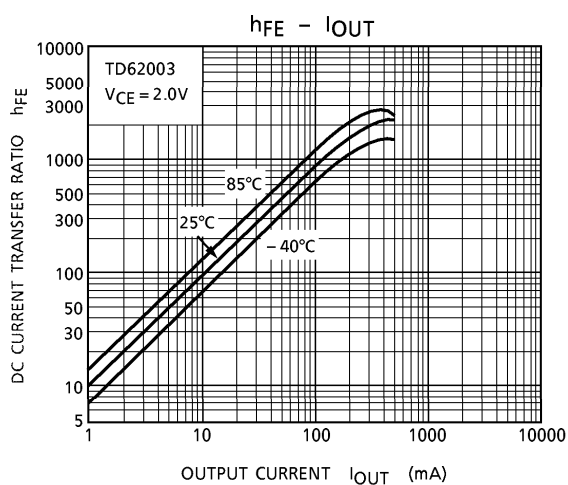
PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



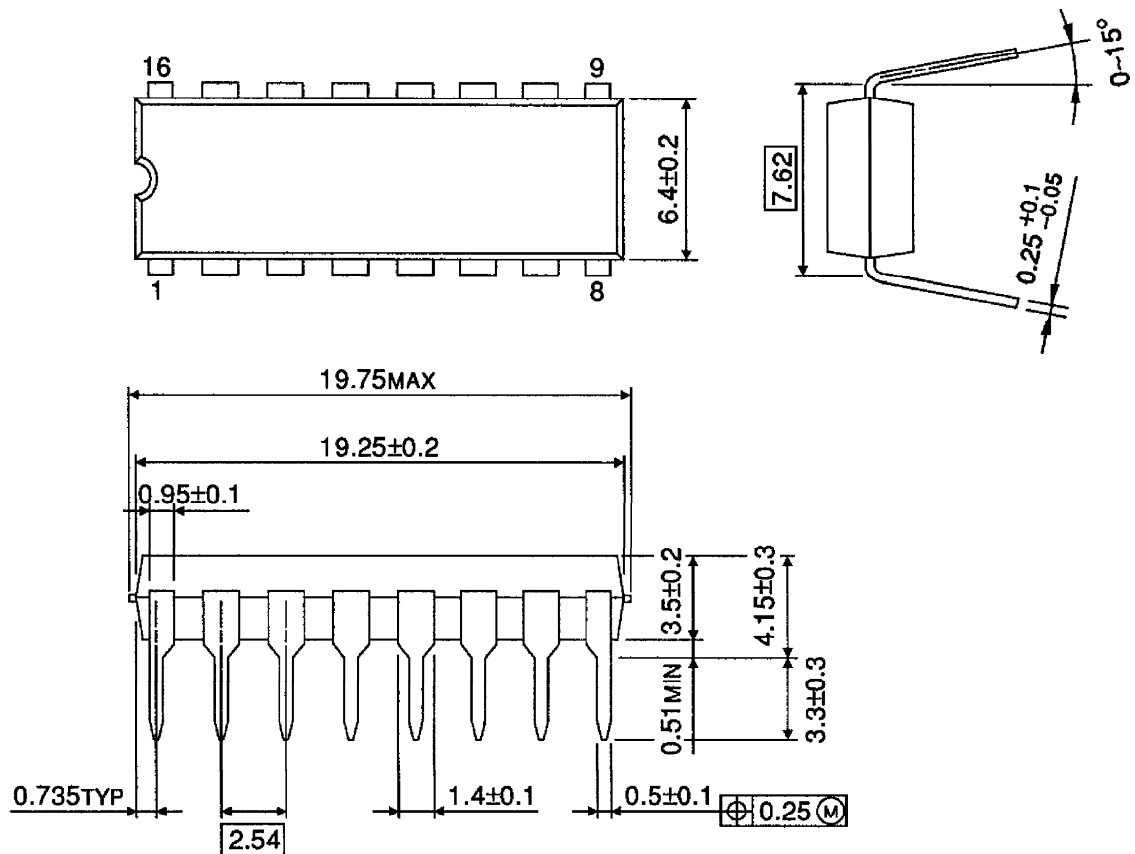






OUTLINE DRAWING
DIP16-P-300-2.54A

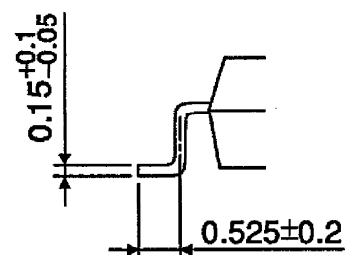
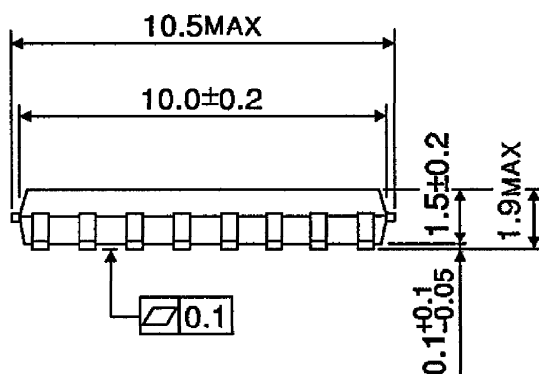
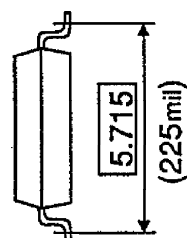
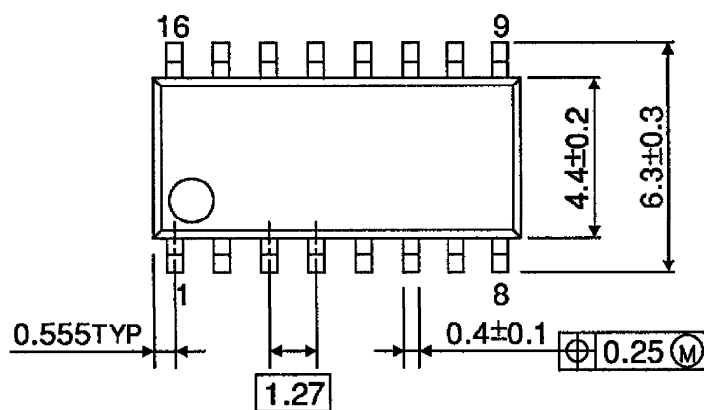
Unit : mm



Weight : 1.11g (Typ.)

OUTLINE DRAWING
SOP16-P-225-1.27

Unit : mm



Weight : 0.16g (Typ.)